

USB OTG Companion Device with V_{BUS} Over Voltage, Over Current Protection, and Four Channel ESD Clamps

 Check for Samples: [TPD4S214](#)

FEATURES

- Input Voltage Protection at V_{BUS} from -7 V to 30 V
- Low $R_{DS(ON)}$ N-CH FET Switch for High Efficiency
- Compliant with USB2.0 and USB3.0 OTG spec
- User Adjustable Current Limit From 250 mA to Beyond 1.2 A
- Built-in Soft-start
- Reverse Current Blocking
- Over Voltage Lock Out for V_{BUS}
- Under Voltage Lock Out for V_{OTG_IN}
- Thermal Shutdown and Short Circuit Protection
- Auto Retry on any Fault; no Latching off States
- Integrated V_{BUS} Detection Circuit
- Low Capacitance TVS ESD Clamp for USB2.0 High Speed Data Rate
- Internal 16ms Startup Delay

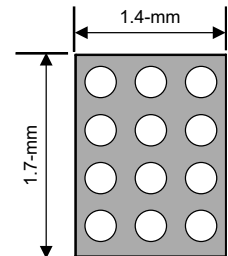
- ESD Performance D+, D-, ID, V_{BUS} PINS
 - $\pm 15\text{-kV}$ Contact Discharge (IEC 61000-4-2)
 - $\pm 15\text{-kV}$ Air Gap Discharge (IEC 61000-4-2)
- Space Saving WCSP (12-YFF) Package

APPLICATIONS

- Cell Phones
- Tablet, eBook
- Set-Top Box
- Portable Media Players
- Digital Camera

YFF PACKAGE
(TOP SIDE/SEE-THROUGH VIEW)

12-YFF Pin Proposal			
	1	2	3
A	V_{OTG_IN}	DET	VBUS
B	V_{OTG_IN}	FLT	VBUS
C	EN	GND	ID
D	ADJ	D-	D+



DESCRIPTION

The TPD4S214 is a single-chip protection solution for USB On-the-Go and other current limited USB applications. This device includes an integrated low ($R_{DS(ON)}$) N-channel current limited switch for OTG current supply to peripheral devices. TPD4S214 offers low capacitance TVS ESD clamps for the D+, D-, ID pins for both USB2.0 and USB3.0 applications. The VBUS pin can handle continuous voltage ranging from -7 V to 30 V . The over voltage lock-out (OVLO) at the VBUS pin ensures that if there is a fault condition at the V_{BUS} line, the TPD4S214 is able to isolate it and protects the internal circuitry from damage. Similarly, the under voltage lock out (UVLO) at the V_{OTG_IN} pin ensures that there is no power drain from the internal OTG supply to external V_{BUS} if V_{OTG_IN} droops below safe operating level.

When EN is high, the OTG switch is activated and the $\overline{\text{FLT}}$ pin indicates whether there is a fault condition. The soft start feature waits 16 ms to turn on the OTG switch after all operating conditions are met. The FLT pin asserts low during any one of the following fault conditions: OVLO ($V_{BUS} > V_{OVLO}$), UVLO condition ($V_{OTG_IN} < V_{UVLO}$) over temperature, over current, short circuit condition, or reverse-current-condition ($V_{BUS} > V_{OTG_IN}$). The OTG switch is turned off during any fault condition. Once the switch is turned off, the IC periodically rechecks the faults internally. If the IC returns to normal operating conditions, the switch turns back on and FLT is reset to high.

There is also a V_{BUS} detection feature for facilitating USB communication between USB host and peripheral device. See Table 2 for detection scheme. If this is not used, DET pin can be either floating or connected to ground.



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	WCSP – YFF (0.4-mm pitch)	Tape and reel	TPD4S214YFFR	B3214

- (1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

CIRCUIT SCHEMATIC DIAGRAM

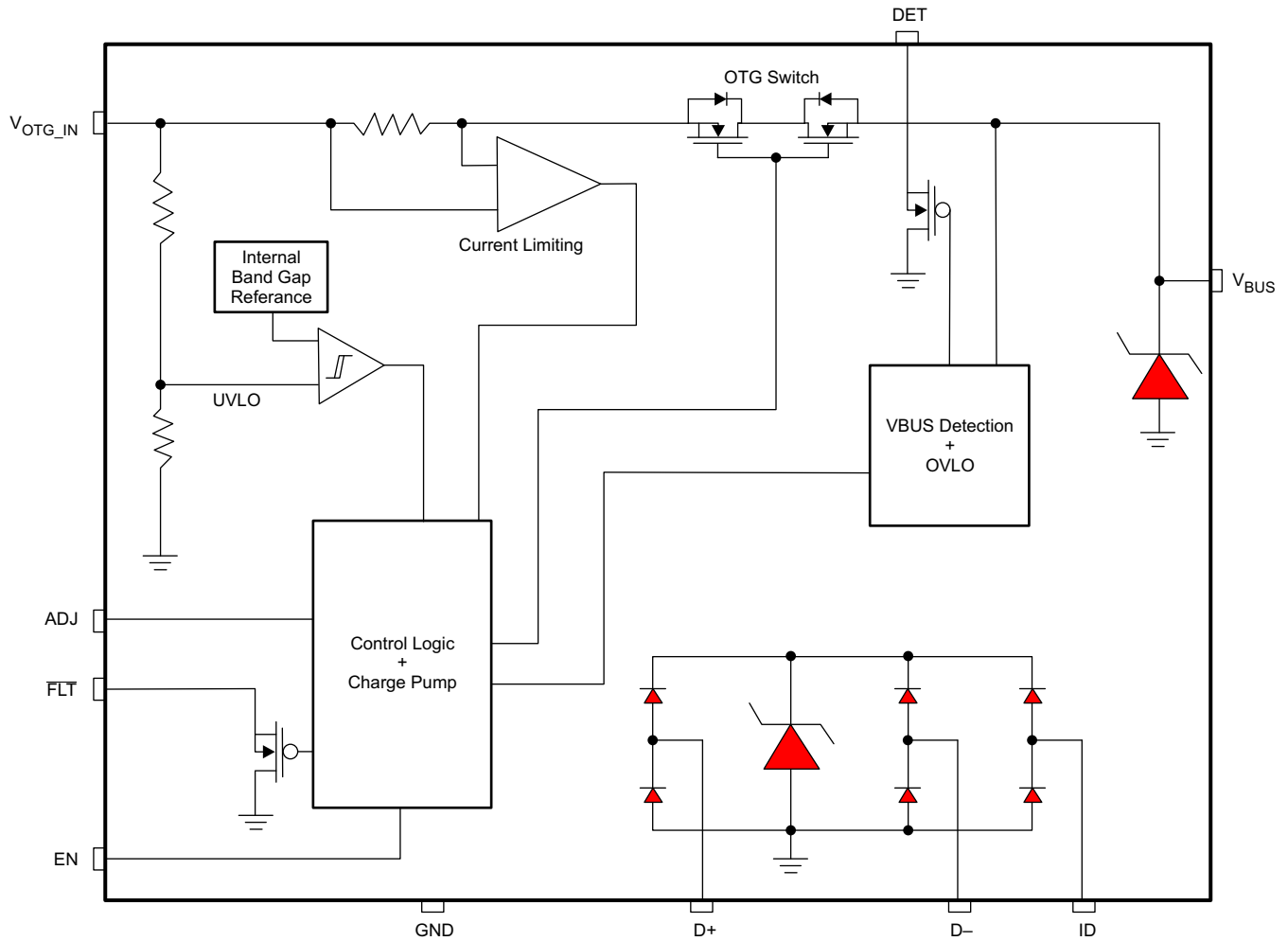


Figure 1. Circuit Schematic

PRODUCT PREVIEW

Table 1. Device Operation

EN	V _{OTG_IN}	V _{BUS}	OCF	OTP	OTG SW	FLT	FAULT CONDITION
X	0	0	F	F	OFF	L	SW Disabled
X	X	X	X	T	OFF	L	Over Temperature
H	X	X	T	X	OFF	L	Over Current
H	V _{OTG_IN} > V _{UVLO}	V _{BUS} > V _{OTG_IN}	F	F	OFF	L	Reverse-current
H	X	V _{BUS} > V _{OVLO}	F	F	OFF	L	V _{BUS} over-voltage
H	V _{OTG_IN} < V _{UVLO}	X	F	F	OFF	L	V _{OTG_IN} under-voltage
H	V _{OTG_IN} > V _{BUS} and V _{OTG_IN} > V _{UVLO}	V _{SHORT} < V _{BUS} < V _{OTG_IN} and V _{SHORT} < V _{BUS} < V _{OVLO}	F	F	ON	H	Normal (SW Enabled)

Table 2. V_{BUS} Detection Scheme⁽¹⁾

EN	V _{OTG_IN} (V _{BUS} Detect Power)	V _{BUS}	DET	Condition
X	X	V _{BUS_VALID-} < V _{BUS} < V _{BUS_VALID+}	H	V _{BUS} within V _{BUS_VALID}
X	X	V _{BUS_VALID+} > V _{BUS} or V _{BUS} > V _{BUS_VALID+}	L	V _{BUS} outside of V _{BUS_VALID}

(1) X = Don't Care, H = Signal High, and L = Signal Low

PIN FUNCTIONS

NAME	PIN			DESCRIPTION
	YFF	DRC	TYPE	
D-	D2	TBD	I/O	USB data-
D+	D3	TBD	I/O	USB data+
ID	C3	TBD	I/O	USB ID signal
FLT	B2	TBD	O	Open-Drain Output. Connect a pullup resistor from FLT to the supply voltage of the host system.
ADJ	D1	TBD	I	Attach external resistor to adjust the current limit
EN	C1	TBD	I	Enable Input. Drive EN high to enable the OTG switch.
V _{BUS}	A3, B3	TBD	O	USB Power Output
V _{OTG_IN}	A1, B1	TBD	I	USB OTG Supply Input
DET	A2	TBD	O	Open-Drain Output. Connect a pullup resistor from DET to the supply voltage of the host system.
GND	C2	Thermal Pad	Ground	Connect to PCB ground plane

PRODUCT PREVIEW

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾⁽²⁾

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{OTG_IN} , ADJ, EN	Input voltage	-0.5	7	V
V _{BUS}	Output voltage to USB connector	-7	30	
FLT, DET	Output voltage	-0.5	7	
	Input clamp current V _I < 0		-50	mA
	I _{OUT} Continuous current through FLT and DET output		10	mA
	I _{GND} Continuous current through GND		100	mA
	T _{J(max)} maximum junction temperature	-65	150	°C
D+, D-, ID, V _{BUS} pins	IEC 61000-4-2 Contact Discharge at 25°C		±15	kV
D+, D-, ID, V _{BUS} pins	IEC 61000-4-2 Air-gap Discharge at 25°C		±15	kV
All pins	Human-Body Model at 25°C		±2	kV
D+, D-, ID pins	Peak Pulse Current (tp = 8/20 μs) at 25°C		7.8	A
D+, D-, ID pins	Peak Pulse Power (tp = 8/20 μs) at 25°C		84	W

- Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

		MIN	TYP	MAX	UNIT	
T _A	Operating free-air temperature	-40		85	°C	
V _{IH}	High-level input voltage EN	1.2			V	
V _{IL}	Low-level input voltage EN			0.4	V	
t _{EN}	EN ramp rate for proper turn on	Valid ramp rate is between 10us and 100ms, rising and falling		0.01	100	ms
t _{UVLO_SLEW}	V _{OTG_IN} ramp rate for proper UVLO operation	Valid ramp rate is between 10us and 100ms, rising and falling		0.01	100	ms
t _{OVLO_SLEW}	V _{BUS} ramp rate for proper OVLO operation	Valid ramp rate is between 10us and 100ms, rising and falling		0.01	100	ms
T _{A_VBUS_ATT}	Time to detect V _{BUS} device attachment and turn on DET			200	ms	

THERMAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

THERMAL METRICS ⁽¹⁾		YFF	UNITS
θ _{JA}	Package thermal impedance	89.1	°C/W

- The published θ_{JA} was modeled assuming a 76mm x 114mm PCB with 4 copper layers and the exposed land pad of the PCB has thermal vias connecting the exposed center pad of the package to an internal GND plane for maximum heat dissipation. For more information about traditional and new thermal metrics, see the IC Package Metrics application report, [SPRA953A](#).

PRODUCT PREVIEW

ELECTRICAL CHARACTERISTICS FOR EN, $\overline{\text{FLT}}$, DET, D+, D–, V_{BUS} , ID Pins

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{\text{IL_EN}}$	EN pin input leakage current	EN = 3.3 V			1	μA
I_{OL}	$\overline{\text{FLT}}$, DET pin output leakage current	$\overline{\text{FLT}}$, DET = 3.6 V			1	μA
$V_{\text{OL_FLT}}$	Low-level output voltage $\overline{\text{FLT}}$	V_{BUS} or $V_{\text{OTG_IN}} = 5 \text{ V}$ or 0 V $I_{\text{OL}} = 100 \mu\text{A}$			100	mV
$V_{\text{OL_DET}}$	Low-level output voltage DET	V_{BUS} and $V_{\text{OTG_IN}} = 5 \text{ V}$ or 0 V $I_{\text{OL}} = 100 \mu\text{A}$			100	mV
C_{EN}	Enable capacitance	$V_{\text{BIAS}} = 1.8 \text{ V}$, $f = 1 \text{ MHz}$, 30 mVpp ripple, $V_{\text{OTG_IN}} = 5 \text{ V}$		4.5		pF
V_{D}	Diode forward voltage D+, D–, ID pins; lower clamp diode	$I_{\text{O}} = 8 \text{ mA}$			0.95	V
$I_{\text{L_D}}$	Leakage current on D+, D–, ID Pins	D+, D–, ID = 3.3 V			100	nA
ΔC_{IO}	Differential capacitance between the D+, D– lines	$V_{\text{BIAS}} = 1.8 \text{ V}$, $f = 1 \text{ MHz}$, 30 mVpp ripple, $V_{\text{OTG_IN}} = 5 \text{ V}$			0.04	pF
C_{IO}	Capacitance to GND for the D+, D– lines	$V_{\text{BIAS}} = 1.8 \text{ V}$, $f = 1 \text{ MHz}$, 30 mVpp ripple, $V_{\text{OTG_IN}} = 5 \text{ V}$		1.9		pF
	Capacitance to GND for the ID lines			1.9		
V_{BR}	Breakdown voltage D+, D–, ID pins	$I_{\text{br}} = 1 \text{ mA}$	6			V
	Breakdown voltage on Vbus	$I_{\text{br}} = 1 \text{ mA}$	33			V
R_{DYN}	Dynamic on resistance D+, D–, ID clamps			1		Ω

ELECTRICAL CHARACTERISTICS FOR UVLO / OVLO

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT UNDER-VOLTAGE LOCKOUT						
$V_{\text{UVLO+}}$	Under-voltage lock-out, input power detected threshold rising	$V_{\text{OTG_IN}}$ increasing from 0 V to 5 V, No load on V_{BUS} pin	3.4	3.6	3.8	V
$V_{\text{UVLO-}}$	Under-voltage lock-out, input power detected threshold falling	$V_{\text{OTG_IN}}$ decreasing from 5 V to 0 V, No load on V_{BUS} pin	3.0	3.2	3.5	V
$V_{\text{HYS-UVLO}}$	Hysteresis on UVLO	Δ of $V_{\text{UVLO+}}$ and $V_{\text{UVLO-}}$		260		mV
T_{RUVLO}	Recovery time from UVLO	$V_{\text{OTG_IN}}$ increasing from 0V to 5V, No load on V_{BUS} pin; time from $V_{\text{OTG_IN}} = V_{\text{UVLO+}}$ to $\overline{\text{FLT}}$ toggles high		18		ms
$T_{\text{RESP_UVLO}}$	Response time for UVLO	$V_{\text{OTG_IN}}$ decreasing from 5V to 0V, No load on V_{BUS} pin; time from $V_{\text{OTG_IN}} = V_{\text{UVLO-}}$ to $\overline{\text{FLT}}$ toggles low		0.18		μs
OUTPUT OVERVOLTAGE LOCKOUT						
$V_{\text{OVP+}}$	OVLO rising threshold	Both $V_{\text{OTG_IN}}$ and V_{BUS} increasing from 5 V to 7 V	5.55	6.15	6.45	V
$V_{\text{OVP-}}$	OVLO falling threshold	Both $V_{\text{OTG_IN}}$ and V_{BUS} decreasing from 7 V to 5 V	5.4	6	6.3	V
$V_{\text{HYS-OVP}}$	Hysteresis on OVLO	Δ of $V_{\text{UVLO+}}$ and $V_{\text{UVLO-}}$		100		mV
T_{ROVLO}	Recovery time from OVLO	Both $V_{\text{OTG_IN}}$ and V_{BUS} decreasing from 7 V to 5 V, $V_{\text{OTG_IN}} = 5 \text{ V}$; time from $V_{\text{BUS}} = V_{\text{OVP-}}$ to $\overline{\text{FLT}}$ toggles high		9		ms
$T_{\text{RESP_OVLO}}$	Response time for OVLO	Both $V_{\text{OTG_IN}}$ and V_{BUS} increasing from 5 V to 7 V, $V_{\text{OTG_IN}} = 5 \text{ V}$; time from $V_{\text{BUS}} = V_{\text{OVP+}}$ to $\overline{\text{FLT}}$ toggles low		17		μs

ELECTRICAL CHARACTERISTICS FOR DET CIRCUITS

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{BUS_VALID-}	Valid V _{BUS} voltage detect	V _{BUS} = 7 V to 0 V			V
V _{BUS_VALID+}	Valid V _{BUS} voltage detect	V _{BUS} = 0 V to 7 V			V
T _{DET_DELAY-}	VBUS detect propagation delay-	VBUS 0 V to 4 V, 200 ns ramp; VBUS = V _{BUS_VALID-} MIN to DET toggles high			μs
T _{DET_DELAY+}	VBUS detect propagation delay+	VBUS 6 V to 4 V, 200 ns ramp; VBUS = V _{BUS_VALID+} MAX to DET toggles low			μs

ELECTRICAL CHARACTERISTICS FOR OTG SWITCH

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
R _{DS_ON}	OTG switch resistance	V _{BUS} = 5 V, I _{OUT} = 100 mA, R _{ADJ} = 75 kΩ ⁽¹⁾			mΩ
V _{DROP}	OTG switch voltage drop	V _{BUS} = 5 V, I _{OUT} = 100 mA, R _{ADJ} = 75 kΩ			mV
I _{OTG_OFF_30V}	Leakage current at 30V	Measured at V _{OTG_IN}	V _{BUS} = 30 V, EN = 5 V, V _{OTG_IN} = 5 V		μA
I _{OTG_OFF_2V}	Leakage current at -2V		V _{BUS} = 30 V, EN = 5 V, V _{OTG_IN} = 0 V		nA
I _{OTG_OFF}	Standby Leakage current		V _{BUS} = -2 V, EN = 5 V, V _{OTG_IN} = 5 V		μA
I _{BUS_REV}	Reverse Leakage current		V _{BUS} = 0 V, EN = 0 V, V _{OTG_IN} = 5 V		μA
			V _{BUS} = 5 V, EN = 0 V, V _{OTG_IN} = 0 V		nA
I _{BUS_REV}	Reverse Leakage current		V _{BUS} = 5 V, EN = 5 V, V _{OTG_IN} = 0V		nA
		V _{BUS} = 5.5 V, EN = 5 V, V _{OTG_IN} = 5 V		μA	
T _{ON}	Turn-ON time	R _L = 100 Ω, C _L = 1 uF, R _{ADJ} = 75 kΩ			ms
T _{OFF_EN}	Turn-OFF time	R _L = 100 Ω, C _L = 1 uF, R _{ADJ} = 75 kΩ, toggle EN			μs
T _{OFF_OTG}	Turn-OFF time	R _L = 100 Ω, C _L = 1 uF, R _{ADJ} = 75 kΩ, toggle V _{OTG_IN}			μs
T _{RISE}	Output rise time	R _L = 100 Ω, C _L = 1 uF, R _{ADJ} = 75 kΩ			μs
T _{FALL}	Output fall time	R _L = 100 Ω, C _L = 1 uF, R _{ADJ} = 75 kΩ			μs

(1) R_{DS_ON} is measured at 25°C

ELECTRICAL CHARACTERISTICS FOR CURRENT LIMIT and SHORT CIRCUIT PROTECTION

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I _{OCP}	Current-limit threshold (maximum DC output current I _{OUT} delivered to load)	V _{OTG_IN} = 5 V	R _{ADJ} = 226 kΩ ⁽¹⁾		mA
			R _{ADJ} = 75 kΩ ⁽¹⁾		
			R _{ADJ} = 62 kΩ ⁽¹⁾		
			R _{ADJ} = 45 kΩ ⁽¹⁾		
T _{BLANK}	Blanking time after enable	V _{OTG_IN} = 5 V		RL = 1 Ω, CL = 1 uF, RADJ = 75 kΩ	ms
T _{DEGL}	Deglitch time while enabled				ms
T _{DET_SC}	Response time to short circuit	V _{OTG_IN} = 5 V, RL = 100 Ω, CL = 1 uF, RADJ = 75 kΩ, apply short to ground			μs
T _{REG}	Short circuit regulation time	Hiccup pulse width; auto-retry time			ms
T _{OCP}	Short circuit over current protection time	Hiccup pulse period			ms
V _{SHORT}	Short circuit threshold				V
I _{INRUSH}	Inrush current during a startup	See Figure 5 under test configuration		RL = 100 Ω, CL = 22 μF, RADJ = 75 kΩ	mA

(1) External resistor tolerance is ±1%

PRODUCT PREVIEW

ELECTRICAL CHARACTERISTICS FOR REVERSE VOLTAGE PROTECTION

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{REV} Reverse-voltage comparator trip point (at V _{BUS} port)	V _{BUS} > V _{OTG_IN}		50		mV
T _{RRVP} Time from reverse-voltage condition to MOSFET switch off and FLG = low			17.5		ms
T _{RREV} Re-arming time			25		μs

SUPPLY CURRENT CONSUMPTION

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TYP	MAX	UNIT
I _{VOTG_INON} High-level V _{OTG_IN} operating current consumption	V _{OTG_IN} = 5 V, No load on V _{BUS} , EN = 5 V	162	200	μA
		150	200	μA

THERMAL SHUTDOWN

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TYP	MAX	UNIT
T _{SHDN+} Shutdown temp rising		141		°C
T _{SHDN-} Shutdown temp falling		125		°C
T _{HYST} Thermal-shutdown Hysteresis		16		°C
P _{MAX} Maximum power dissipation	V _{OTG_IN} = 5 V, R _{load} = 5 Ω, EN = 5 V, R _{ADJ} = 75 kΩ		0.16	W
T _{JMAX} Junction Temp at max power dissipation			150	°C

APPLICATION DIAGRAM

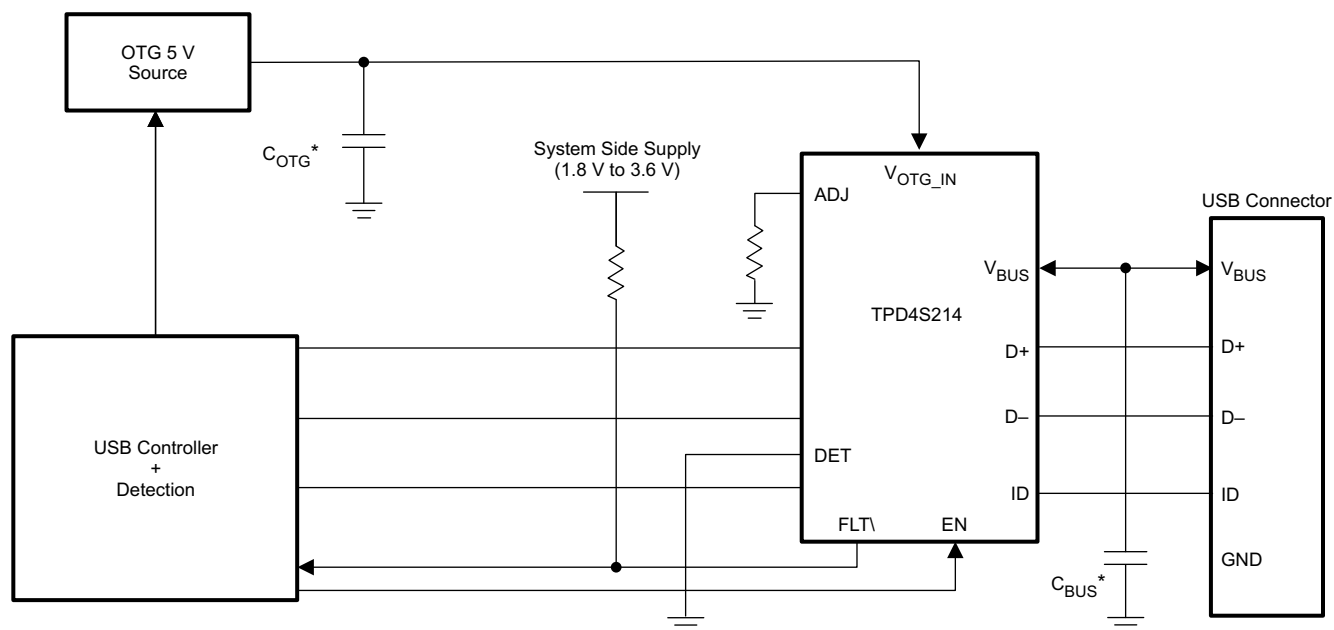


Figure 2. USB2.0 Application Diagram Without Using On-chip V_{BUS} Detect

PRODUCT PREVIEW

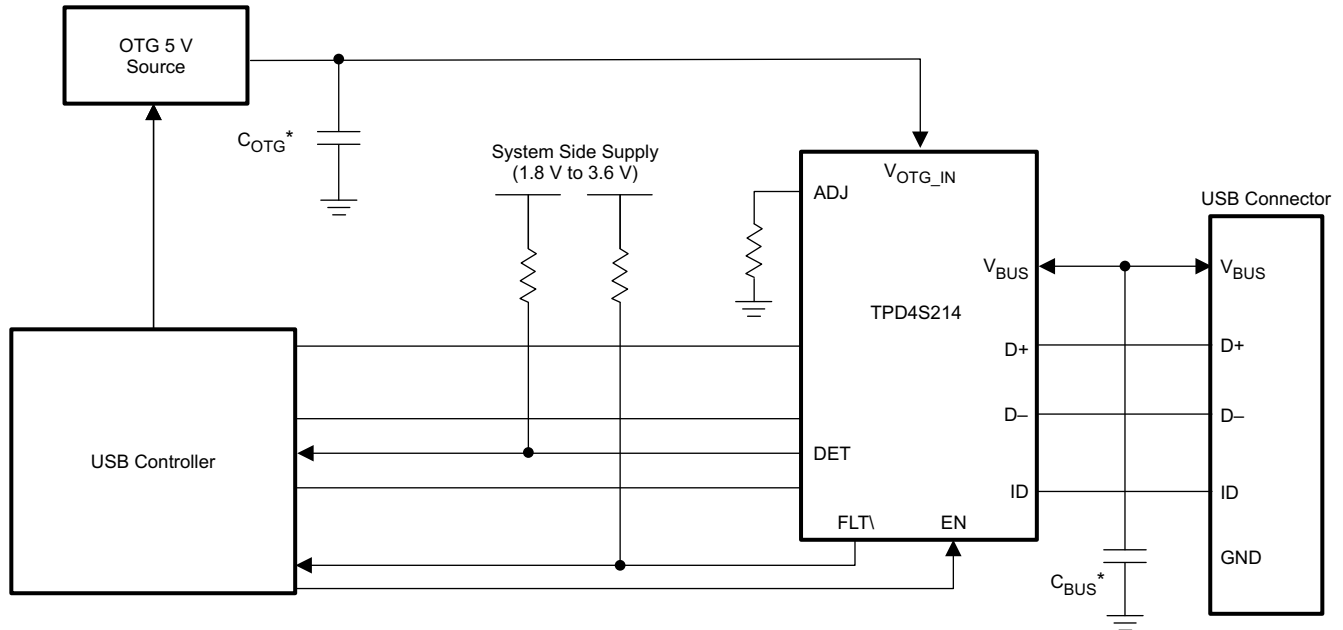
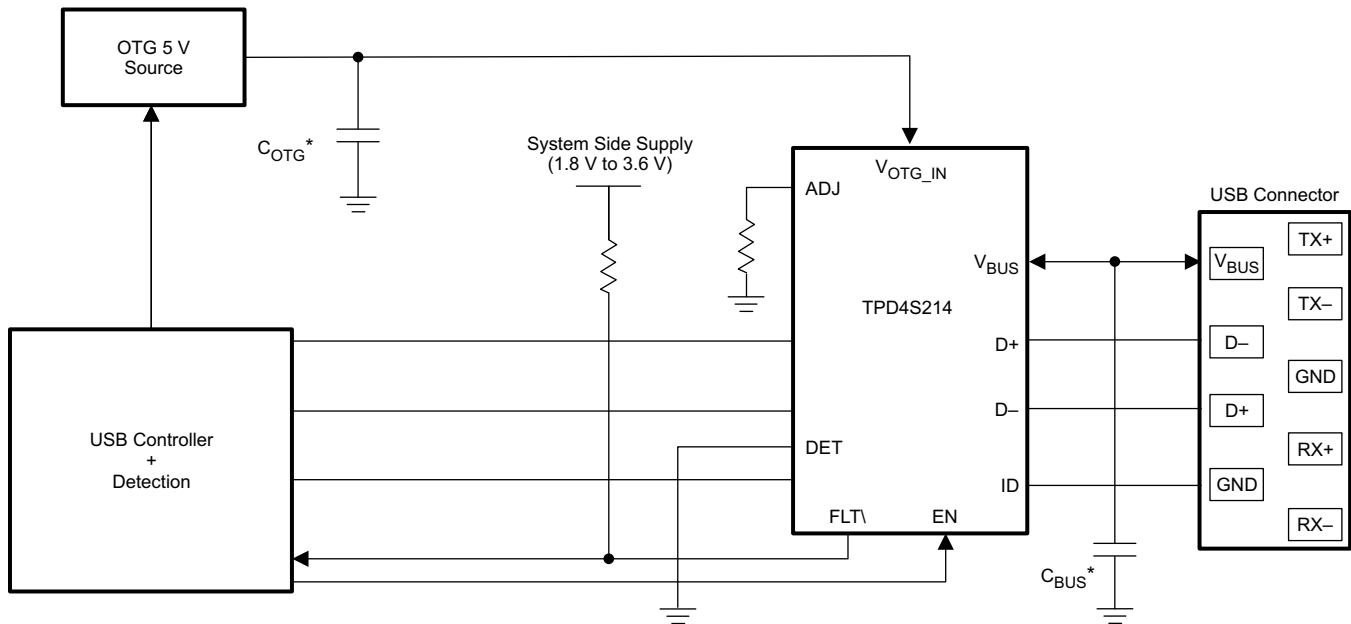


Figure 3. USB 2.0 Application Diagram Using On-chip V_{BUS} Detect



*C_{BUS} and C_{OTG} have minimum recommended values of 1 μF each

Figure 4. USB 3.0 Application Diagram Without Using On-chip V_{BUS} Detect

PRODUCT PREVIEW

TEST CONFIGURATION

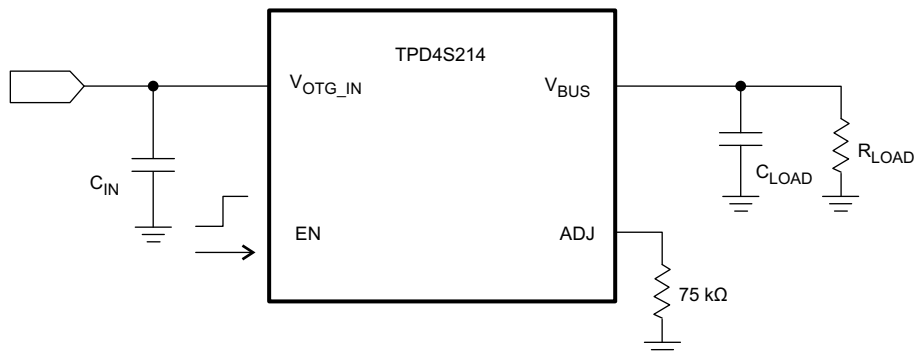


Figure 5. Inrush Current Test Configuration.

Enable is toggled from low to high. See the [Application Information](#) section for C_{IN} and C_{LOAD} value recommendations.

PRODUCT PREVIEW

TYPICAL CHARACTERISTICS

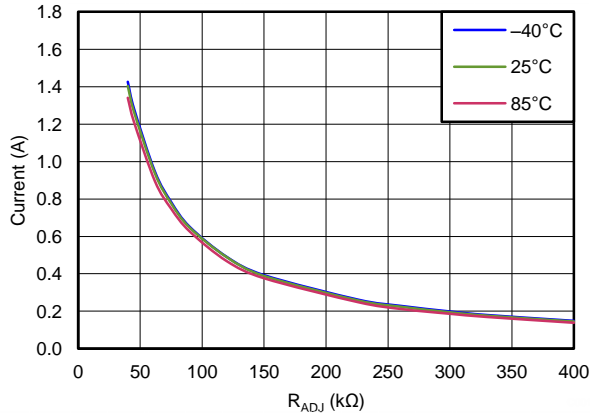


Figure 6. I_{OCP} vs. R_{ADJ}

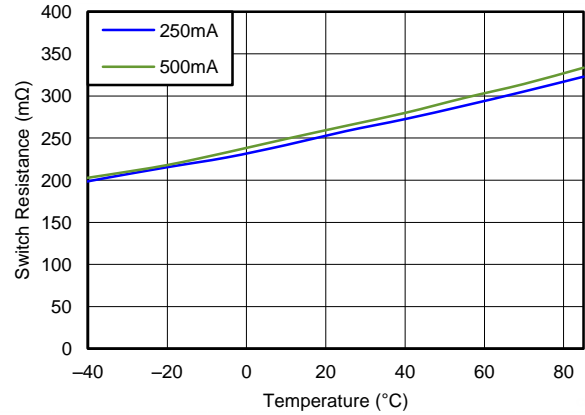


Figure 7. $3R_{DS(on)}$ vs. Temperature

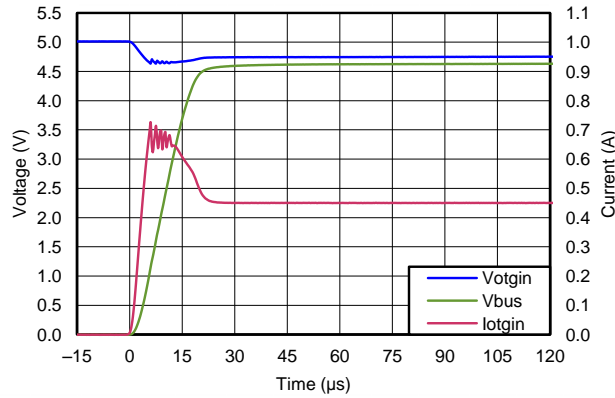


Figure 8. Inrush, $R_{ADJ} = 75 \text{ k}\Omega$

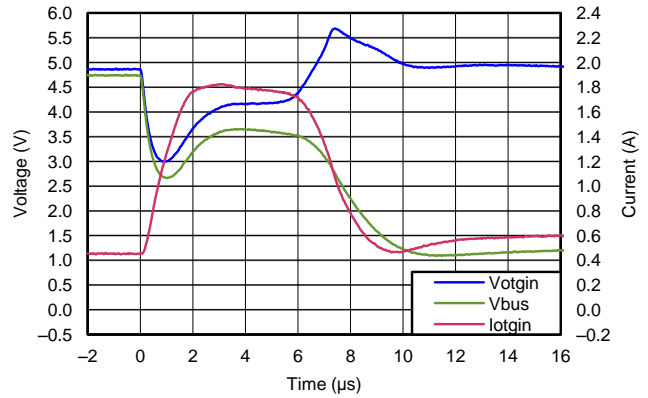


Figure 9. 10Ω Load to Short, $2 \mu\text{s}$

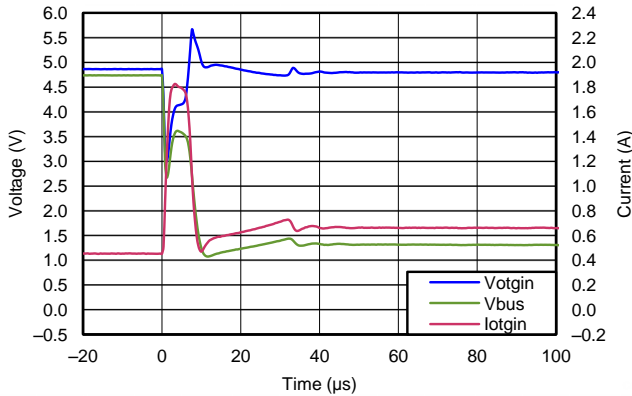


Figure 10. 10Ω Load to Short, $20 \mu\text{s}$

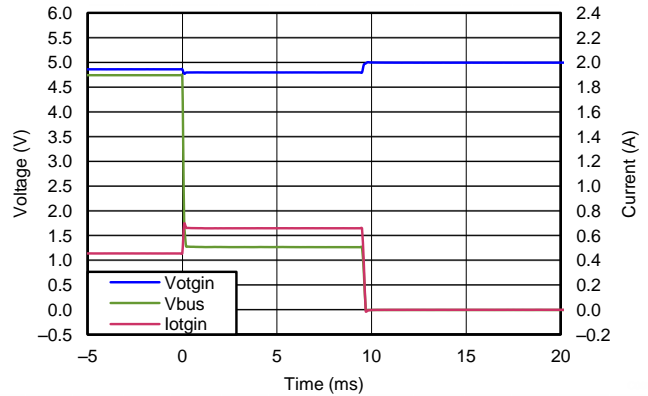


Figure 11. 10Ω Load to Short, 5 ms

PRODUCT PREVIEW

TYPICAL CHARACTERISTICS (continued)

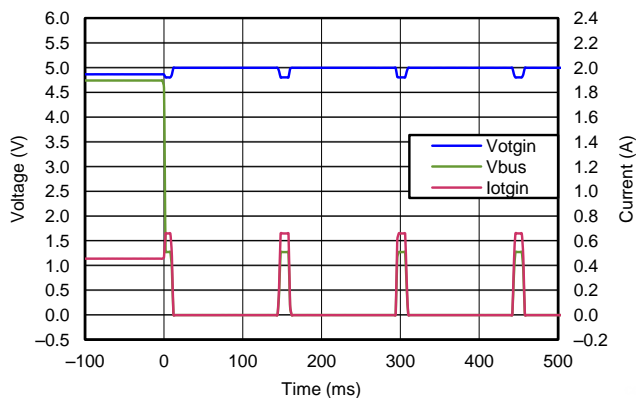


Figure 12. 10 Ω Load to Short, 100 ms

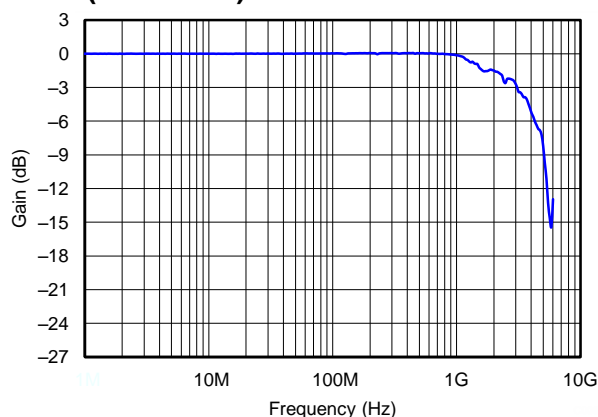


Figure 13. Data Line Insertion Loss

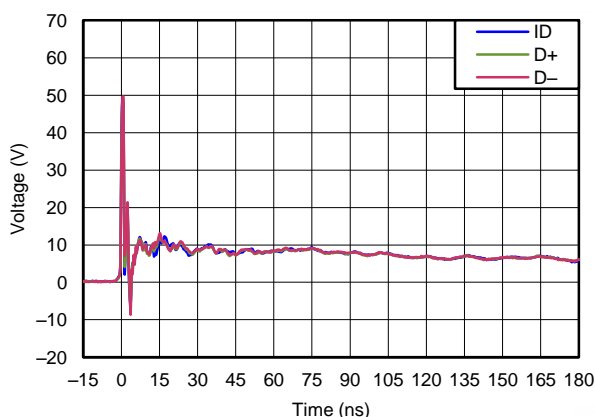


Figure 14. +8 kV Contact, 1 GHz

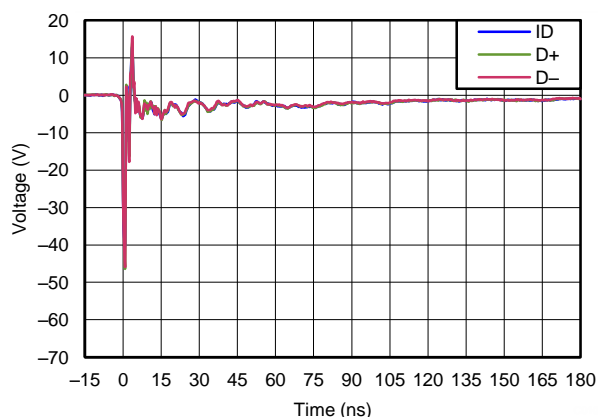


Figure 15. -8 kV Contact, 1 GHz

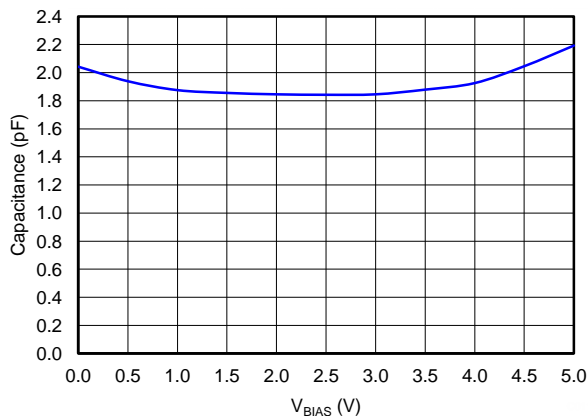


Figure 16. C_{IO} vs. V_{BIAS} , $f = 1$ MHz

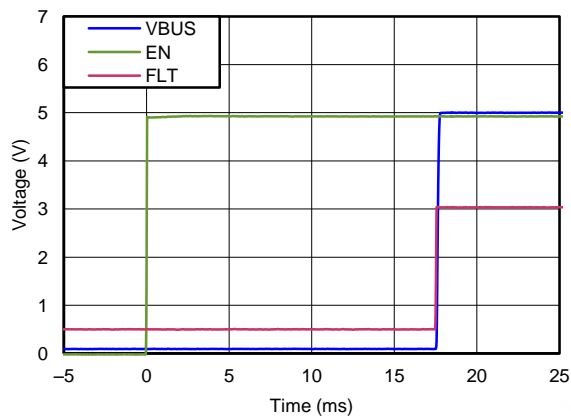


Figure 17. TPD4S214 Turn On Characteristics

PRODUCT PREVIEW

TYPICAL CHARACTERISTICS (continued)

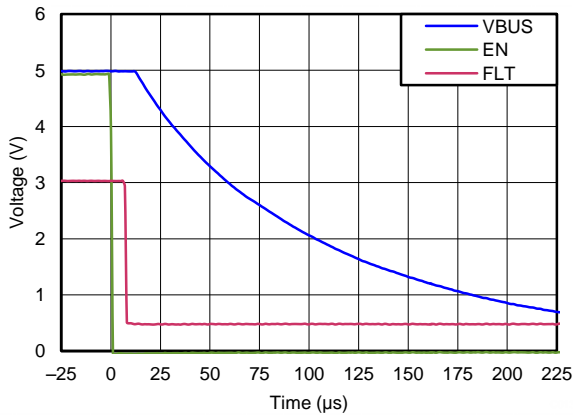


Figure 18. TPD4S214 Turn Off Characteristics

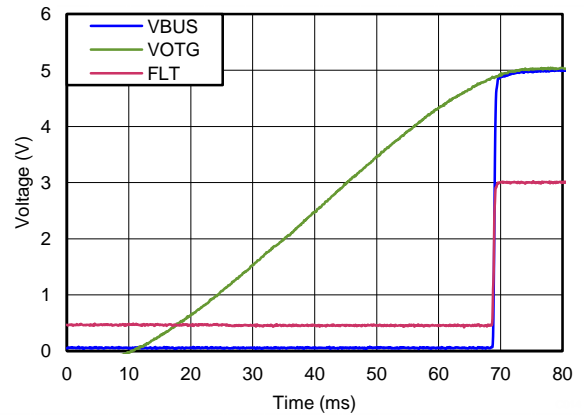


Figure 19. UVLO

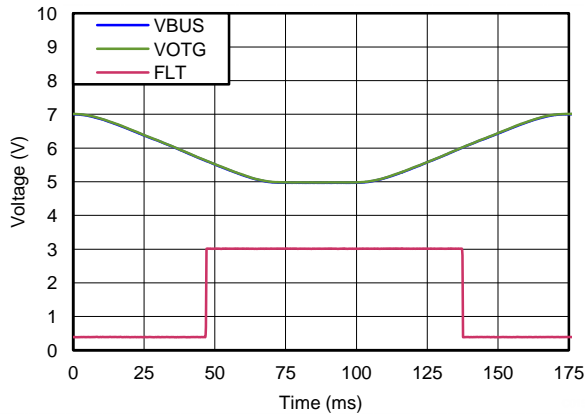


Figure 20. OVLO

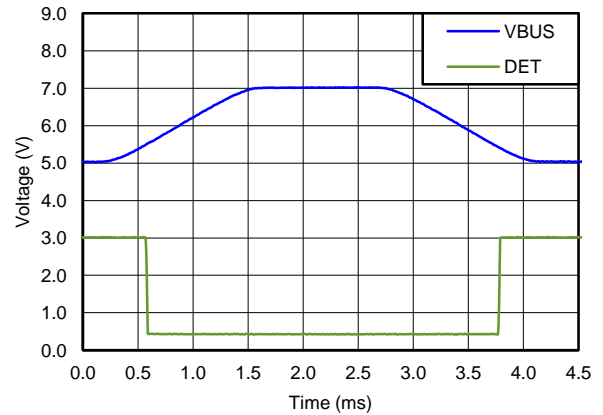


Figure 21. V_{BUS} Valid Detect Upper

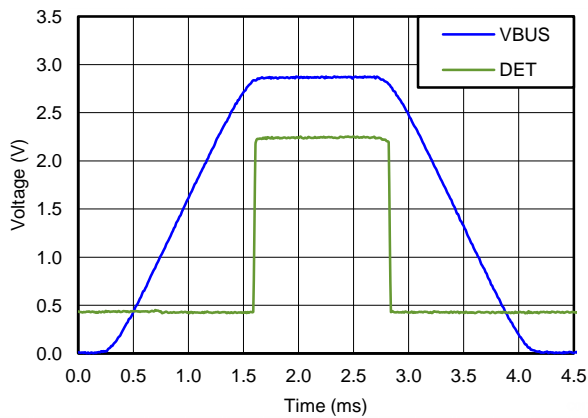


Figure 22. V_{BUS} Valid Detect Lower

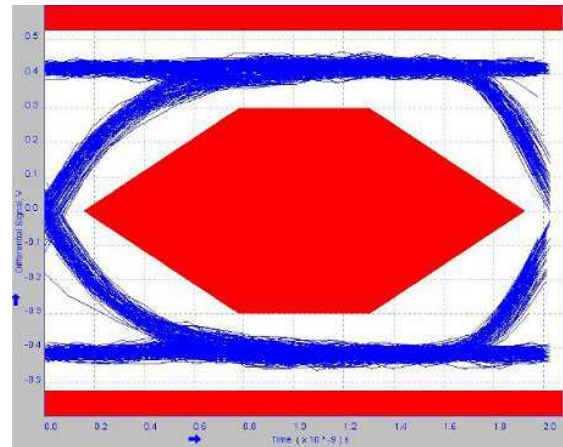


Figure 23. Eye Diagram with no EVM and no IC, Full USB2.0 Speed at 480 Mbps

PRODUCT PREVIEW

TYPICAL CHARACTERISTICS (continued)

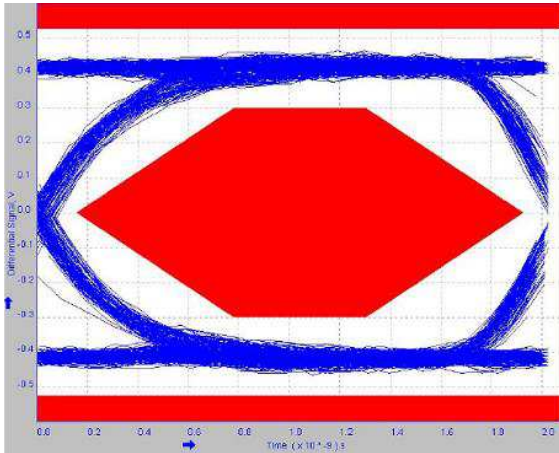


Figure 24. Eye Diagram with TPD4S214EVM but no IC, Full USB2.0 Speed at 480 Mbps

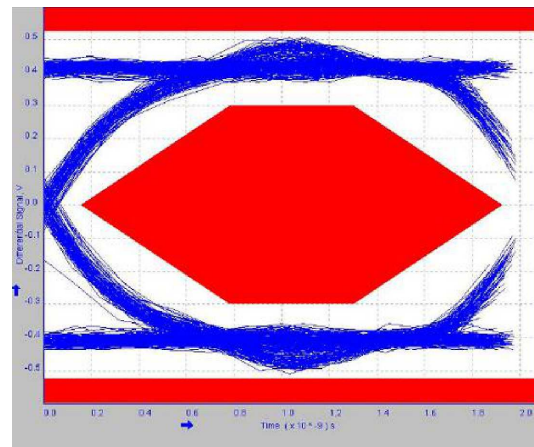


Figure 25. Eye Diagram with TPD4S214EVM and IC, Full USB2.0 Speed at 480 Mbps

APPLICATION INFORMATION

A USB OTG device's one and only connector is the AB receptacle, which accepts either an A or B plug. When an A-plug is inserted, the OTG device is called the A-device and when a B-plug is inserted it is called the B-device. A-device is often times referred to as "Targeted Host" and B-device as "USB peripheral". TPD4S214 supports an OTG device when TPD4S214's system is acting as an A-device and powering the USB interface. The TPD4S214 may also be used in non-OTG applications where it resides on the current source side.

Inrush Current Protection

As soon as TPD4S214 is enabled, its logic block detects the presence of any fault conditions highlighted in [Table 1](#). In the absence of any fault condition, a counter waits for 16 ms, after which a trickle charge of 1 μ A slowly turns on the main switch. During the inrush period, the peak inrush current will be limited to no more than the current limit set by the external resistor R_{ADJ} .

INPUT CAPACITOR (OPTIONAL)

To limit the voltage drop on the input supply caused by transient in-rush currents when the switch turns on into a discharged load capacitor or short-circuit, a capacitor needs to be placed between V_{OTG_IN} and GND. A 10- μ F ceramic capacitor, C_{IN} , placed close to the pins, is usually sufficient. Higher values of C_{IN} can be used to further reduce the voltage drop during high-current application. When switching heavy loads, it is recommended to have an input capacitor about 10 times higher than the output capacitor to avoid excessive voltage drop.

OUTPUT CAPACITOR (OPTIONAL)

Due to the integrated body diode in the NMOS switch, a C_{IN} greater than C_{LOAD} is highly recommended. A C_{LOAD} greater than C_{IN} can cause V_{BUS} to exceed V_{OTG_IN} when the system supply is removed. A C_{IN} to C_{LOAD} ratio of 10 to 1 is recommended for minimizing V_{OTG_IN} dip caused by inrush currents during startup.

Current Limit

The TPD4S214 provides current limiting function, which is set by an external resistor connected from the ADJ pin to ground shown in [Figure 26](#). The current limiting threshold I_{OCP} is set by the external resistor R_{ADJ} . [Figure 6](#) shows the minimum, typical, and maximum current limit for a corresponding R_{ADJ} value with $\pm 1\%$ tolerance.

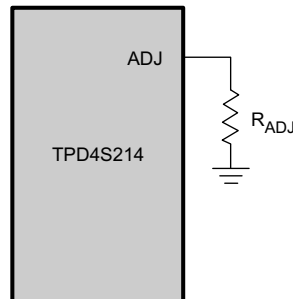


Figure 26.

$$R_{ADJ} = \frac{55.358}{I_{OCP}} \quad (1)$$

Where:

R_{ADJ} = external resistor used to set the current limit (k Ω)

I_{OCP} = current limit set by the external R_{ADJ} resistor (A)

R_{ADJ} is placed between the ADJ pin and ground, shown in the figure above, providing a minimum current limit between 250 mA and 1.2 A.

V_{BUS} Detection

There are several important protocols defined in [OTG and EH Supplement] that governs communication between Targeted Hosts (A-device) and USB peripherals (B-device). Communication between host and peripheral is usually done on the ID pin only. In case when two OTG devices that could both act as either host or peripheral are connected, measuring voltage level on V_{BUS} will aid in the handshaking process. If an embedded host instead of a USB device is connected to the OTG device, OTG charging would not be required and the system's OTG source should remain off to conserve power. The TPD4S214 V_{BUS} detection block aids power conservation and is powered from V_{BUS}. See figure 3. The DET pin is an open drain PMOS output with default state low.

In the event when an A-plug is attached, the system detects ID pin as FALSE, in which case ID pin resistance to ground is less than 10 Ω. For a B-plug, the system detects ID pin as TRUE and ID pin resistance to ground is greater than 100 kΩ. For the system to power a USB device through OTG switch once it is connected, voltage on V_{BUS} should remain below V_{BUS_VALID MIN} within T_{A_VBUS_ATT} of the ID pin becoming FALSE. After this event, the system confirms that the USB device requires power and enables both TPD4S214 and OTG source. However, if V_{BUS_VALID} is detected on V_{BUS} within T_{A_VBUS_ATT} of the ID pin becoming FALSE, there is either a system error or the device connected does not require charging. OTG source remains switched off and the entire sequence would restart when the system detects another FALSE on the ID pin.

Table 3. V_{BUS} Detection scheme

EN	V _{OTG_IN} (V _{BUS} Detect Power)	V _{BUS}	DET	Condition
X	X	V _{BUS_VALID-} < V _{BUS} < V _{BUS_VALID+}	H	V _{BUS} within V _{BUS_VALID}
X	X	V _{BUS_VALID-} > V _{BUS} or V _{BUS} > V _{BUS_VALID+}	L	V _{BUS} outside of V _{BUS_VALID}

Figure 27 and Figure 28 shows suggested system level timing diagram for detecting V_{BUS} according to [OTG and EH Supplement]. Figure 3 shows the application diagram. In Figure 27, DET pin remains low after ID pin becomes FALSE, indicating there is not an active voltage source on V_{BUS}. The USB controller proceeds to turn on OTG 5V source and the TPD4S214 respectively; this sequence is recommended because TPD4S214 is powered through the OTG source. After a period of t_{ON}, current starts to flow through the OTG switch and V_{BUS} is ramped to the voltage level of V_{OTG_IN}.

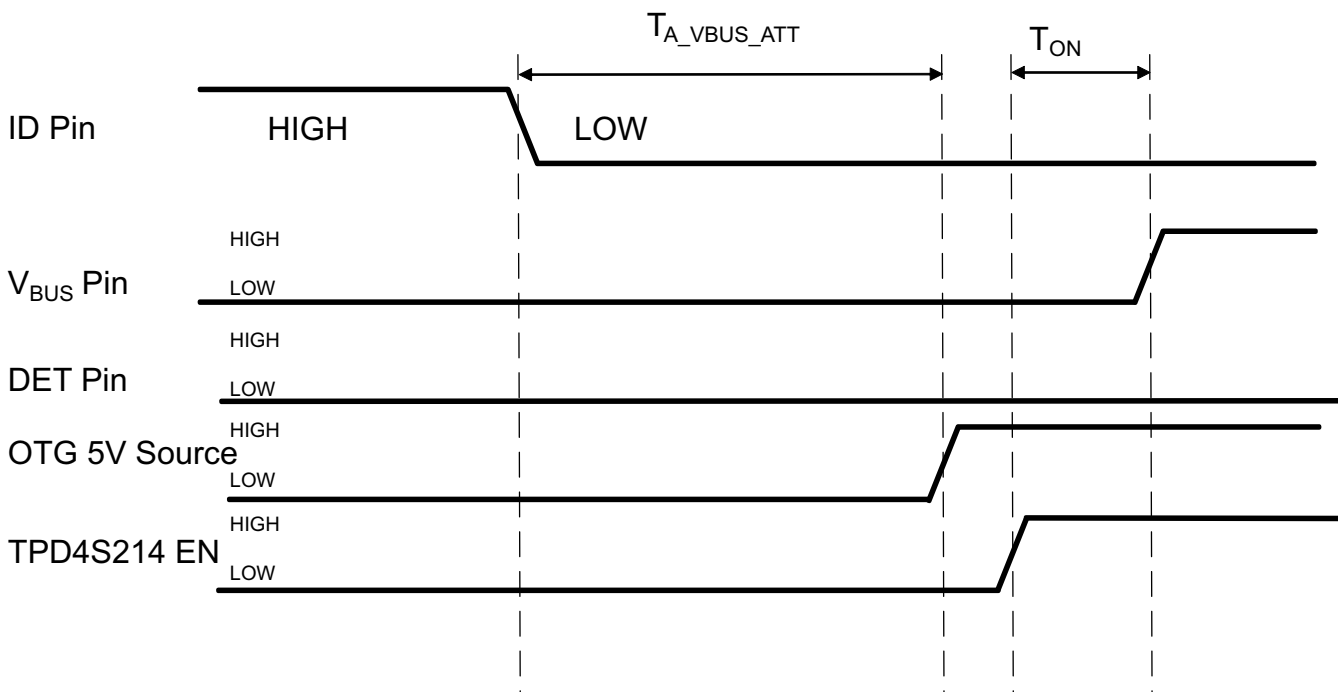


Figure 27. Timing Diagram for Valid USB Device

In Figure 28, DET pin toggles high after an active voltage is detected on V_{BUS} within $T_{A_VBUS_ATT}$. This indicates that the USB device attached is not suitable for OTG charging and both OTV 5V source and TPD4S214 remain off.

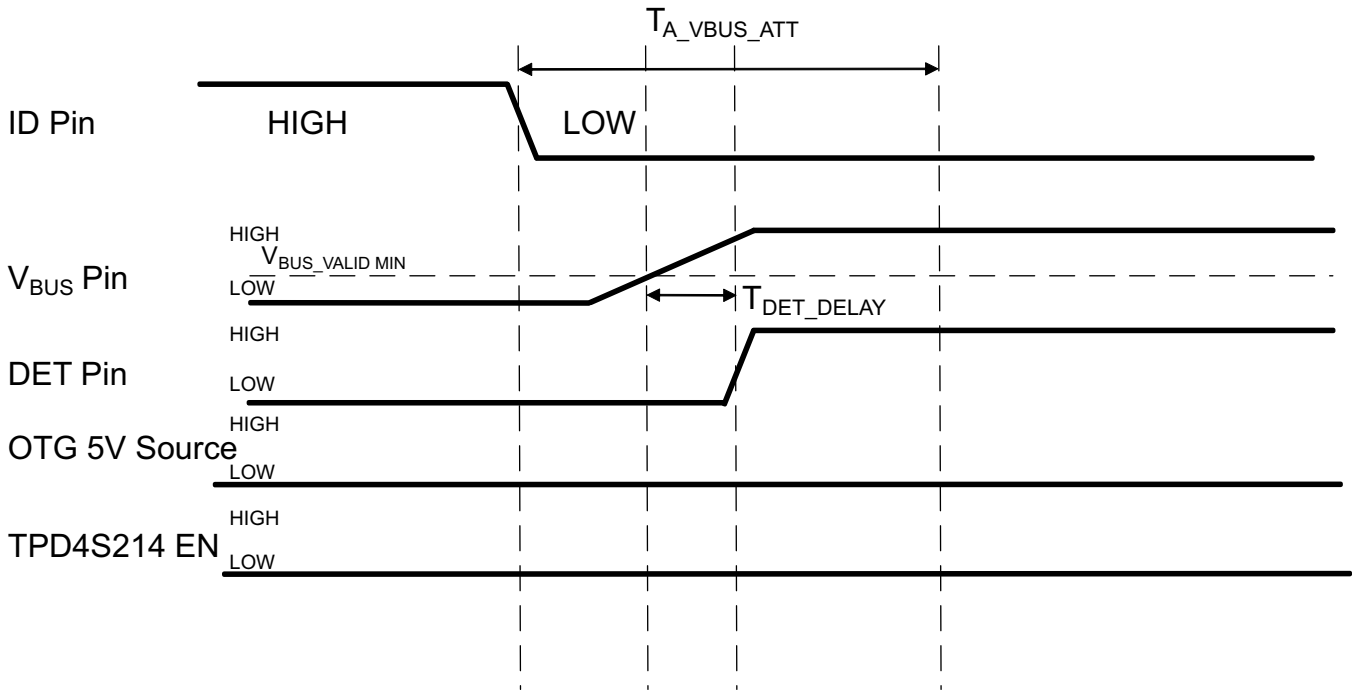


Figure 28. System Level Timing Diagram for invalid USB Device

Related Documents

OTG and EH Supplement] *On-The-Go and Embedded Host Supplement to the USB Revision 2.0 Specification*, July 14th, 2011. www.usb.org

PRODUCT PREVIEW

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TPD4S214AYFFR	PREVIEW	DSBGA	YFF	12	3000	TBD	Call TI	Call TI	-40 to 85		
TPD4S214YFFR	PREVIEW	DSBGA	YFF	12	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

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